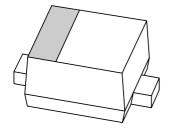
DISCRETE SEMICONDUCTORS

DATA SHEET



PMEG2010AEB

20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

Product data sheet 2003 Dec 03



20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

PMEG2010AEB

FEATURES

Forward current: 1.0 AReverse voltage: 20 VUltra low forward voltage

• Ultra small SMD package.

APPLICATIONS

• Low voltage rectification

• High efficiency DC/DC conversion

· Voltage clamping

• Inverse-polarity protection

• Low power consumption applications.

DESCRIPTION

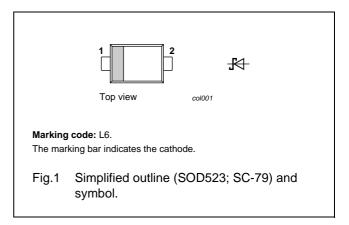
Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD523 (SC-79) ultra small plastic SMD package.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
IF	forward current	1	Α
V_R	reverse voltage	20	٧

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



ORDERING INFORMATION

TYPE NUMBER		PACKAGE		
TIPE NOWIBER	NAME DESCRIPTION		VERSION	
PMEG2010AEB	_	plastic surface mounted package; 2 leads	SOD523	

RELATED PRODUCTS

TYPE	DESCRIPTION	FEATURE
PMEG2005EB	0.5 A; 20 V very low V _F MEGA Schottky rectifier	Lower I _R in same package
PMEG2010EA	1 A; 20 V very low V _F MEGA Schottky rectifier	Lower forward current, lower I _R SOD323 (SC76)

20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

PMEG2010AEB

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	20	V
I _F	continuous forward current	T _s ≤ 55 °C	_	1.0	Α
I _{FRM}	repetitive peak forward current	$t_p \le 1$ ms; $\delta \le 0.5$	_	3.5	Α
I _{FSM}	non-repetitive peak forward current	t = 8 ms square wave	_	6	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	note 1	_	150	°C
T _{amb}	operating ambient temperature	note 1	-65	+150	°C

Note

 For Schottky barrier rectifiers, thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and I_{F(AV)} rating will be available on request.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air; notes 1 and 2	400	K/W
R _{th(j-s)}	thermal resistance from junction to soldering point	notes 2 and 3	75	K/W

Notes

- 1. Refer to SOD523 (SC-79) standard mounting conditions.
- For Schottky barrier rectifiers, thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and I_{F(AV)} rating will be available on request.
- 3. Solder point of cathode tab.

20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

PMEG2010AEB

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 0.1 mA	30	60	mV
		I _F = 1 mA	80	110	mV
		I _F = 10 mA	140	190	mV
		I _F = 100 mA	230	290	mV
		I _F = 1000 mA	510	620	mV
I _R	continuous reverse current	V _R = 10 V; note 1	0.17	0.6	mA
		V _R = 20 V; note 1	0.32	1.5	mA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz	19	25	pF

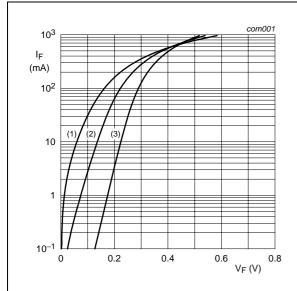
Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

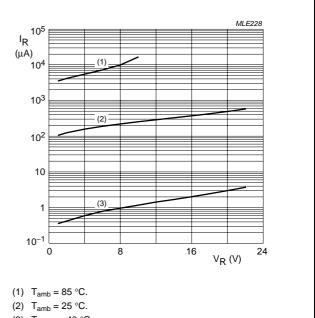
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GRAPHICAL DATA



- (1) $T_{amb} = 85 \,^{\circ}C$.
- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = -40 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



(3) $T_{amb} = -40 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.

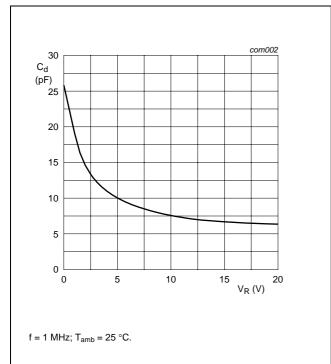


Fig.4 Diode capacitance as a function of reverse voltage; typical values.

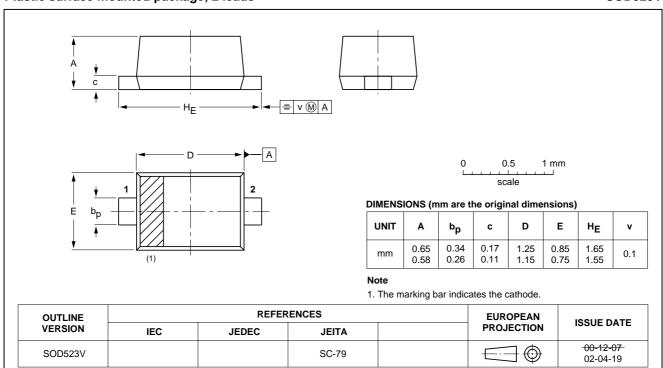
20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

PMEG2010AEB

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD523V



20 V, 1 A ultra low V_F MEGA Schottky barrier rectifier in SOD523 package

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published
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